imall

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10A, 50V - 600V Isolated Glass Passivated Super Fast Rectifiers

FEATURES

- Glass passivated chip junction
- High efficiency, Low VF
- High surge current capability
- High current capability
- High reliability
- UL Recognized File # E-326243
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

MECHANICAL DATA

Case: ITO-220AC Molding compound: UL flammability classification rating 94V-0 Part no. with suffix "H" means AEC-Q101 qualified Packing code with suffix "G" means green compound (halogen-free) Terminal: Matte tin plated leads, solderable per JESD22-B102 Meet JESD 201 class 2 whisker test Polarity: As marked Mounting torque: 0.56 Nm max. Weight: 1.7 g (approximately)



0

0

PIN 1

PIN 2





MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS (T _A =25°C unless otherwise noted)										
PARAMETER	SYMBOL	SFAF	SFAF	SFAF	SFAF	SFAF	SFAF	SFAF	SFAF	UNIT
						1005G				
Maximum repetitive peak reverse voltage	V _{RRM}	50	100	150	200	300	400	500	600	V
Maximum RMS voltage	V_{RMS}	35	70	105	140	210	280	350	420	V
Maximum DC blocking voltage	V _{DC}	50	100	150	200	300	400	500	600	V
Maximum average forward rectified current	I _{F(AV)}	10					A			
Peak forward surge current, 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	150					А			
Maximum instantaneous forward voltage (Note 1) I _F = 10 A	V _F	0.975 1.3		1.7		V				
Maximum reverse current @ rated V_R T _J =25°C T _J =100°C	I _R	10 400					μA			
Maximum reverse recovery time (Note 2)	t _{rr}	35					ns			
Typical junction capacitance (Note 3)	CJ	170 140			pF					
Typical thermal resistance	$R_{ extsf{ heta}JC}$	4				°C/W				
Operating junction temperature range	TJ	- 55 to +150			°C					
Storage temperature range	T _{STG}	- 55 to +150			°C					
	•									•

Note 1: Pulse test with PW=300 μ s, 1% duty cycle

Note 2: Test conditions: I_F =0.5A, I_R =1.0A, I_{RR} =0.25A

Note 3: Measured at 1 MHz and applied reverse voltage of 4.0V DC.



SFAF1001G - SFAF1008G

Taiwan Semiconductor

ORDERING INFORMATION

••••••						
PART NO.	PART NO.	PACKING	PACKING CODE	PACKAGE	PACKING	
TAIL NO.	SUFFIX	CODE	SUFFIX ^(*)	TAORAGE	FAORING	
SFAF100xG (Note 1)	Н	C0	G	ITO-220AC	50 / Tube	

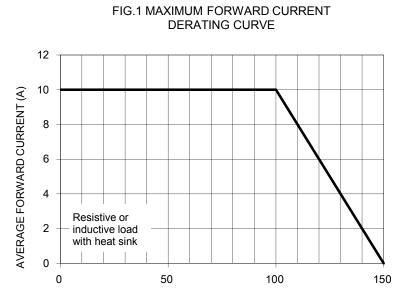
Note 1: "x" defines voltage from 50V (SFAF1001G) to 600V (SFAF1008G)

*: Optional available

EXAMPLE PACKING CODE PART NO. PACKING CODE **EXAMPLE P/N** PART NO. DESCRIPTION SUFFIX SUFFIX AEC-Q101 qualified SFAF1001GHC0G SFAF1001G Н C0 G Green compound

RATINGS AND CHARACTERISTICS CURVES

(T_A=25°C unless otherwise noted)





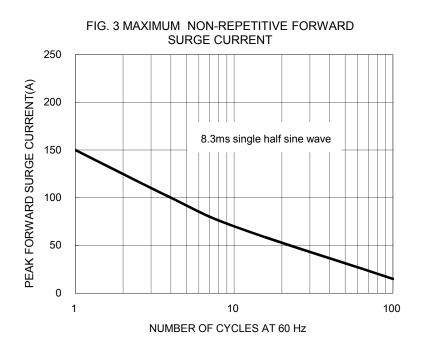
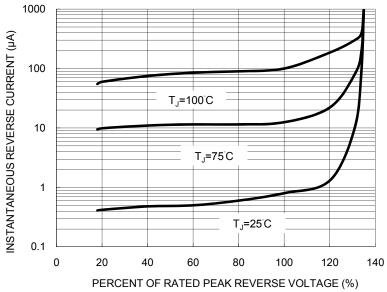
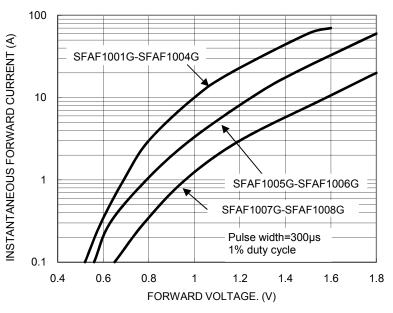


FIG. 2 TYPICAL REVERSE CHARACTERISTICS









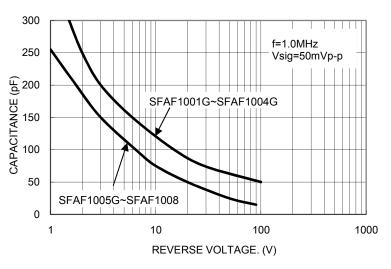
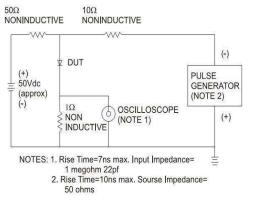
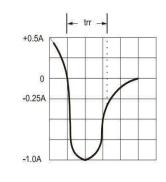


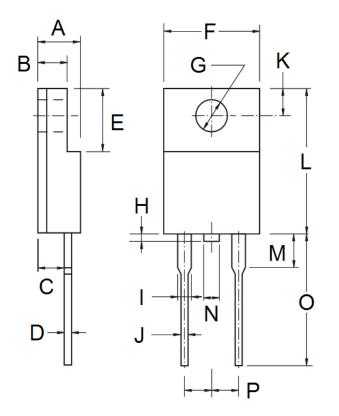
FIG. 5 TYPICAL JUNCTION CAPACITANCE

FIG.6 REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM





PACKAGE OUTLINE DIMENSIONS ITO-220AC



G

F

DIM.	Unit	(mm)	Unit (inch)			
DIM.	Min	Max	Min	Max		
А	4.30	4.70	0.169	0.185		
В	2.50	3.10	0.098	0.122		
С	2.30	2.90	0.091	0.114		
D	0.46	0.76	0.018	0.030		
E	6.30	6.90	0.248	0.272		
F	9.60	10.30	0.378	0.406		
G	3.00	3.40	0.118	0.134		
Н	0.00	1.60	0.000	0.063		
I	0.95	1.45	0.037	0.057		
J	0.50	0.90	0.020	0.035		
К	2.40	3.20	0.094	0.126		
L	14.80	15.50	0.583	0.610		
М	-	4.10	-	0.161		
Ν	-	1.80	-	0.071		
0	12.60	13.80	0.496	0.543		
Р	4.95	5.20	0.195	0.205		

MARKING DIAGRAM

SS 91 GYWWF	
P/N	

- P/N = Specific Device Code
 - = Green Compound
- YWW = Date Code
 - = Factory Code



Taiwan Semiconductor

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